



Take advantage of wideband, low noise Medium power UMS PH10 GaAs process

United Monolithic Semiconductors is opening a shared foundry run on PH10 GaAs process.

The launch date for the Multi-Project Wafer is July 19, 2024.

PH10 PHEMT GaAs process is optimized for the production of low noise, wideband and medium power amplifier MMICs operating up to 110GHz.

Designers using **PH10** can design Low Noise, Variable Gain Amplifiers, Medium Power Amplifiers, mixers and multi-functions TX and RX MMICs for various applications including E-band Communication radios, Automotive radars, Imaging sensors, Optical fibre communication and Instrumentation.

PH10 can combine power and low noise performance on a single chip for compact systems with an entry price of 2 300€/mm².

What are the main characteristics of PH10?

| ELEMENT | PARAMETER | VALUE | CONDITIONS | |
|----------------------|------------------------------------|-------|------------------------------|--|
| FET | Idss (mA/mm) | 280 | Vds = 2.0V, Vgs = 0V | |
| | Gm (mS/mm) | 750 | Vds = 2.0V, Vgs = 0V | |
| | Vbds (V) | 6 | Ids = Idss / 100 | |
| | Vp(V) | -0.45 | Vds = 2.0V, Ids = Idss / 100 | |
| | Ft (cut off freq.) (GHz) | 130 | | |
| MIM Cap. | Density (pF/mm²) | 330 | @ 1 MHz | |
| MIM Cap High Density | Density (pF/mm²) | 625 | @ 1 MHz | |
| TaN Resistor | Sheet Resistance (Ω/\Box) | 30 | | |
| TiWSi Resistor | Sheet Resistance (Ω/\Box) | 1000 | | |
| GaAs Resistor | Sheet Resistance (Ω/\Box) | 120 | | |
| Wafer thickness | μm | 70 | | |

Examples of microwave performance achieved by UMS catalogue MMICs designed on PH10 process:

| Part Number | Freq (GHz) | Gain (dB) | Noise | P-1dB (dBm) | Case |
|---------------------|------------|-----------|-------|-------------|------|
| Low noise amplifier | | | | | |
| CHA2080-98 | 3F 71-86 | 22 | 3.5 | 11 | Die |
| CHA1008-99 | 9F 80-105 | 17 | 5 | 5 | Die |
| Mixer - RX | | | | | |
| CHM1080-98 | 3F 71-85 | -9 | | 9 | Die |
| CHR 1080-98 | RF 71-86 | 6 | 5 | _ | Die |

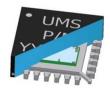
| Part Number | Freq (GHz) | Gain (dB) | Noise | P-1dB (dBm) | Case | | |
|------------------------|------------|-----------|-------|-------------|------|--|--|
| Medium power amplifier | | | | | | | |
| CHA3080-98F | 71-76 | 16 | 4.3 | 19 | Die | | |
| CHA3090-98F | 81-86 | 13 | 4.5 | 17 | Die | | |







By choosing standard MMIC dimensions which are compatible with QFN high volume packaging capability, your project is on track for future industrial success.



How to participate to this shared foundry run?

So to start designing, please apply <u>on-line</u> for process Design Kit. Before the deadline, please send your layout to: <u>foundry@ums-rf.com</u>

| INFORMATION | Lowest cost guaranteed Simply provide your layout before July 19, 2024 | | | | |
|---|--|-----|-----|-----|---|
| DELIVERY | 20 chips | | | | |
| CONDITIONING | Gel-Pak® | | | | |
| AVAILABLE DIE SIZE (mm) | 1 | 1,4 | 2,4 | 3,4 | 4 |
| MAX RATIO | 1:3 | | | | |
| Die size include 70μm dicing street - Launching date flexibility is +/- 2 weeks | | | | | |

Dieframes for layout can be provided on request

Minimum order is 4mm² - Price is valid until July 19, 2024

Order to be placed before July 5, 2024

Important Notes:

- UMS may cancel the run in case of insufficient number of participants.
- For some countries a specific dedicated export license may be required before delivery.

| | 1 | 1.4 | 2.4 | 3.4 | 4 |
|-----|-----|-----|-----|------|------|
| 1 | 1 | 1.4 | 2.4 | | |
| 1.4 | 1.4 | 2 | 3.4 | 4.8 | 5.6 |
| 2.4 | 2.4 | 3.4 | 5.8 | 8.2 | 9.6 |
| 3.4 | | 4.8 | 8.2 | 11.6 | 13.6 |
| 4 | | 5.6 | 9.6 | 13.6 | 16 |

PH10 available die size (mm) including 70µm dicing street

How many dies will I receive and how much does it cost?

You will receive 20 dies of your circuit in Gel-Pak® box from a PH10 PCM good wafer. The price is based on your circuit dimensions on the mask tile multiplied by the mm² unit price. For example, if your circuit is 1.4 x 3.4 mm², the price is 1.4 x 3.4 x 2 300€ = 10 948€.

Which processes are regularly offered in shared foundry?

